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DECLARATION

As a below named inventor, I hereby declare that:

is attached hereto.

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or the below named inventors are the original, first and joint inventors (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled METHOD OF FORMING A GATE ELECTRODE ON A SEMICONDUCTOR DEVICE AND A DEVICE INCORPORATING SAME, the Specification of which:

☐ wa	s filed on	as Application	Serial No		
I hereby staincluding the claims.	ate that I have	reviewed and under	stand the contents of	the above-identified specification	ation,
	ity of the subjec			all information known to me eriality" is defined in Title 37,	
patent, United States	provisional app on for patent, Ui	lication(s), or inventonited States provision	or's certificate listed be	19 of any foreign application(selow and have also identified bentor's certificate having a filing	elow
	PRI	ORITY APPLICAT	ION(S)	Priority Claimed	
(Number)	(Cour	itry)	(Date Filed)	Yes/No	
(Number)	(Cour	try)	(Date Filed)	Yes/No	
listed below and, inse United States applicated acknowledge the duty claimed in this applied	ofar as the subjection in the man y to disclose all cation, as "mate	ct matter of each of ner provided by the information known t eriality" is defined in	the claims of this applifirst paragraph of Tit. o me to be material to Title 37, Code of F	of any United States application is not disclosed in the le 35, United States Code, § 10 patentability of the subject mederal Regulations, § 1.56, which is a possible of the subject mederal Regulations, § 1.56, which is a possible of the subject mederal Regulations, § 1.56, which is a possible of the subject medians.	prior 12, I natter which
(Application	n Serial No.)	(Filing Date)	(Status)		
(Application	Serial No.)	(Filing Date)	(Status)		
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I hereby direct that all correspondence and telephone calls be addressed to J. Mike Amerson, Williams, Morgan & Amerson, P.C., 7676 Hillmont, Suite 250, Houston, Texas 77040, (713) 934-4055.



I HEREBY DECLARE THAT ALL STATEMENTS MADE OF MY OWN KNOWLEDGE ARE TRUE AND THAT ALL STATEMENTS MADE ON INFORMATION AND BELIEF ARE BELIEVED TO BE TRUE; AND FURTHER THAT THESE STATEMENTS WERE MADE WITH THE KNOWLEDGE THAT WILLFUL FALSE STATEMENTS AND THE LIKE SO MADE ARE PUNISHABLE BY FINE OR IMPRISONMENT, OR BOTH, UNDER SECTION 1001 OF TITLE 18 OF THE UNITED STATES CODE AND THAT SUCH WILLFUL FALSE STATEMENTS MAY JEOPARDIZE THE VALIDITY OF THE APPLICATION OR ANY PATENT ISSUED THEREON.

Inventor's Full Name:	William R. Roche			
Inventor's Signature:	William Poll			
Country of Citizenship:	U.S.A.	Date:	9-27-00	
Residence Address: (street,	15575 SW Beverly Beach Court			
number, city, state, and/or country)	Beaverton, Oregon 97007			
Post Office Address: (if different from above)	Same as above			
Inventor's Full Name:	David Donggang Wu			
Inventor's Signature:				
Country of Citizenship:	U.S.A.	Date:		
Residence Address: (street,	12345 Almeda Trace Circle			
number, city, state, and/or country)	Austin, Texas 78727			
Post Office Address: (if different from above)	Same as above			
Inventor's Full Name:	Massud Aminpur			
Inventor's Signature:				
Country of Citizenship:	Germany	Date:		
Residence Address: (street,	Leisinger Str. 31			
number, city, state, and/or country)	Dresden, Germany			
Post Office Address: (if different from above)	Same as above			

Inventor's Full Name:	Scott D. Luning		
Inventor's Signature:			
Country of Citizenship:	U.S.A.	Date:	·
Residence Address: (street, number, city, state, and/or country)	1104 Mission Ridge		
	Austin, Texas 78740		
Post Office Address: (if different from above)	Same as above		

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material to pat	_			information known to me to be eriality" is defined in Title 37.
patent, United any foreign app	States provisional appolication for patent, Ur he application on which	lication(s), or inventor lited States provisional h priority is claimed:	's certificate listed below application, or inventor's	of any foreign application(s) for and have also identified below s certificate having a filing date
	PRIC	ORITY APPLICATION	ON(S)	Priority Claimed
(Number)	(Cour	try)	(Date Filed)	Yes/No
(Number)	(Coun	try)	(Date Filed)	Yes/No
listed below an United States a acknowledge the claimed in this	nd, insofar as the subject population in the man the duty to disclose all application, as "mate ole between the filing of	ct matter of each of the ner provided by the f information known to eriality" is defined in	re claims of this applications paragraph of Title 35 me to be material to pat Title 37, Code of Feder	ny United States application(s) on is not disclosed in the prior in United States Code, § 112, I tentability of the subject matter al Regulations, § 1.56, which PCT international filing date of
(Appl	ication Serial No.)	(Filing Date)	(Status)	
(Appl	ication Serial No.)	(Filing Date)	(Status)	
I here	by direct that all corre	espondence and teleph	one calls be addressed to	o J. Mike Amerson, Williams.

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Inventor's Full Name:	William R. Roche	
Inventor's Signature:		
Country of Citizenship:	U.S.A.	Date:
Residence Address: (street,	22 Northeast Tandem Way, Apt. 179	
number, city, state, and/or country)	~Hillsboro, Oregon 97124	
Post Office Address: (if different from above)	Same as above	
Inventor's Full Name:	David Donggang Wu	
Inventor's Signature:	& delpa the	
Country of Citizenship:	U.S.A.	Date: 7-24-00
Residence Address: (street,	12345 Almeda Trace Circle / 0222	
number, city, state, and/or country)	Austin, Texas 78727 Austin	Tx 78759 DW.
Post Office Address: (if different from above)	Same as above	,
Inventor's Full Name:	Massud Aminpur	
Inventor's Signature:		
Country of Citizenship:	Germany	Date:
Residence Address: (street,	Leisinger Str. 31	
number, city, state, and/or country)	Dresden, Germany	
Post Office Address: (if different from above)	Same as above	

Inventor's Full Name:	Scott D. Luning		
Inventor's Signature:	Scott Dla	m'no	
Country of Citizenship:	U.S.A.	Date:	8-28-00
Residence Address: (street,	1104 Mission Ridge		
number, city, state, and/or country)	Austin, Texas 78740		
Post Office Address:	Same as above		
(if different from above)			

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☐ was	filed on	as Application S	Serial No		
I hereby state including the claims.	te that I have rev	riewed and underst	and the contents of	f the above-identifi	ed specification,
I acknowledg material to patentabil Code of Federal Regu	ity of the subject		nd Trademark Offic this application, as		
I hereby clain patent, United States pany foreign application before that of the appl	provisional applicant of the part of the patent, Unite	ation(s), or inventor d States provisiona		elow and have also	identified below
	PRIOR	ITY APPLICATION	ON(S)		Priority Claimed
(Number)	(Country	')	(Date Filed)		Yes/No
(Number)	(Country	")	(Date Filed)		Yes/No
I hereby clai listed below and, inso United States applicat acknowledge the duty claimed in this applic become available bety this application:	far as the subject tion in the manner to disclose all infeation, as "materia	matter of each of the provided by the formation known to ality" is defined in	irst paragraph of Ti me to be material Title 37, Code of I	plication is not discluded the 35, United State to patentability of the Federal Regulations	losed in the prior es Code, § 112, I he subject matter s, § 1.56, which
(Application	Serial No.)	(Filing Date)	(Status)		
(Application	Serial No.)	(Filing Date)	(Status)		
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Morgan & Amerson, P.C., 7676 Hillmont, Suite 250, Houston, Texas 77040, (713) 934-4055.



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Inventor's Full Name:	William R. Roche	
Inventor's Signature:		
Country of Citizenship:	U.S.A.	Date:
Residence Address: (street, number, city, state, and/or country)	22 Northeast Tandem Way, Apt. 179 Hillsboro, Oregon 97124	
Post Office Address: (if different from above)	Same as above	
Inventor's Full Name: Inventor's Signature:	David Donggang Wu	
Country of Citizenship:	U.S.A.	Date:
Residence Address: (street, number, city, state, and/or country)		Date.
Post Office Address: (if different from above)	Same as above	
Inventor's Full Name: Inventor's Signature:	Massud Aminpur Masor L Pry	
Country of Citizenship:	Germany	Date: 8/4/00
Residence Address: (street, number, city, state, and/or country)	Leisinger Str. 31 Dresden, Germany	
Post Office Address: (if different from above)	Same as above	

Scott D. Luning		
U.S.A.	Date:	
1104 Mission Ridge		
Austin, Texas 78740		
Same as above		
	U.S.A. 1104 Mission Ridge Austin, Texas 78740	U.S.A. Date: 1104 Mission Ridge Austin, Texas 78740

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In re Application of:

WILLIAM R. ROCHE DAVID DONGGANG WU MASSUD AMINPUR SCOTT D. LUNING

Serial No.: Unknown

Filed: Concurrently Herewith

For: METHOD OF FORMING A GATE

ELECTRODE ON A SEMICONDUCTOR

DEVICE AND A DEVICE INCORPORATING SAME

Examiner: Unknown

Group Art Unit: Unknown

Att'y Docket: 2000.032200/TT3634

POWER OF ATTORNEY

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

The undersigned, being the inventors named in the above-identified application, hereby revoke any previous Powers of Attorney and appoint:

Elizabeth A. Apperley, Reg. No. 36,428; Paul S. Drake, Reg. No. 33,491; Louis A. Riley, Reg. No. 39,817; Richard J. Roddy, Reg. No. 27,688; William D. Zahrt II, Reg. No. 26,070; and Harry A. Wolin, Reg. No. 32,638 of Advanced Micro Devices, Inc.; and

Danny L. Williams, Reg. No. 31,892; Terry D. Morgan, Reg. No. 31,181; J. Mike Amerson, Reg. No. 35,426; Kenneth D. Goodman, Reg. No. 30,460; Barbara S. Kitchell, Reg. No. 33,928; Jeffrey A. Pyle, Reg. No. 34,904; Randall C. Furlong, Reg. No. 35,144; Scott F. Diring, Reg. No. 35,119; George J. Oehling, Reg. No. 40,471; Shelley P.M. Fussey, Reg. No. 39,458; Mark D. Moore, Reg. No. 42,903; Carolanne M. King, Reg. No. 44,914; Louis H. Iselin, Reg. No. 42,684; and Raymund F. Eich, Reg. No. 42,508 of Williams, Morgan & Amerson, P.C.,

as its attorney or agent so long as they remain with such firms, with full power of substitution and revocation, to prosecute the application, to make alterations and amendments therein, to transact all business in the Patent and Trademark Office in connection therewith, and to receive any Letters Patent, and for one year after issuance of such Letters Patent to file any request for a certificate of correction that may be deemed appropriate.

Please direct all communications as follows:

J. Mike Amerson WILLIAMS, MORGAN & AMERSON, P.C. 7676 Hillmont, Suite 250 Houston, Texas 77040 (713) 934-4050

Signature:	William R. Roche	Date: 9/22/60
Signature:	David Donggang Wu	Date:
Signature:	Scott D. Luning	Date:
Signature:	Massud Aminpur	Date:



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In re Application of:

WILLIAM R. ROCHE DAVID DONGGANG WU MASSUD AMINPUR

SCOTT D. LUNING

Serial No.: Unknown

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William R. Roche	
Signature: Declear lhe	Date: 7-24-00
David Donggang Wu	·
Signature: Scott D. Jaming	Date: 8 - 28 - 00
Scott D. Luning	
Signature:	Date:
Massud Aminpur	

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In re Application of:

WILLIAM R. ROCHE DAVID DONGGANG WU MASSUD AMINPUR

SCOTT D. LUNING

Serial No.: Unknown

Filed: Concurrently Herewith

For:

METHOD OF FORMING A GATE

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DEVICE AND A DEVICE INCORPORATING SAME

Examiner: Unknown

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